

## Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 TEL: 281-870-8822EMAIL:Sales@DynamicEngineers.com

#### VCTCXO-2.5-3.2-LVCMOS-31.3MHz

LVCMOS Voltage Controlled Temperature Compensated Crystal Oscillator

#### **Features and Benefits**

2.5mm x 3.2m x 1.6mm compact SMD package Up to ±1ppm stability (over -40°C to +85°C) LVCMOS output 3.3V supply Integrated phase jitter performance of 1.5pS RMS Low power consumption

#### **Typical Applications**

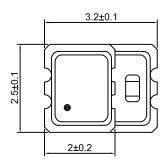
WiMax, WLAN Telecommunication Mobile phone

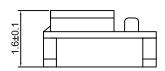
#### **Description**

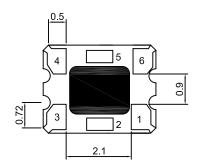
Compact voltage controlled temperature compensated crystal oscillators with outstanding stability and phase jitter performance.

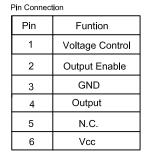
### **Mechanical Drawing & Pin Connections**

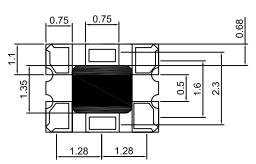
### Drawing No:MD160046-1











Unit: mm 1mm=0.0394inch



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## **Specifications**

General Specifications at Ta = +25°C, CL = 15pFOscillator										
Supply Voltage V <sub>DD</sub>			3.3V ±5%							
Operating Frequency			31.300000 MHz							
Frequency Stability			±1.0 ppm over -40°C to +85°C							
Vs. Temperature (ref to +25°C)										
Vs, Voltage (±5%) input change			±0.2 ppm max							
Vs. Load (±10%) condition change			±0.2 ppm max							
Vs. Aging (per year at 25°C)			1.0 ppm max							
Vs. Reflow (1 reflow and measured 24			1.0 ppm max							
hours afterwards)										
Current Consumption			$V_{DD} = +3.3V$							
All values are typical and over the			50 MHz : 26 mA							
operating temperature			125 MHz : 30 mA							
			200 MHz : 34mA							
Current with Output Disabled			18 mA (typical)							
Load			15 pF							
Output Logic										
High "1"			90% V <sub>DD</sub>							
Low "0"			10% V <sub>DD</sub>							
Rise Time / Fall Time			1.5 nS (typical), 3.0 nS (max)							
			Tr / Tf: 10% ↔ 90% waveform							
Initial Calibration Tolerance			±1.0 ppm max at +25°C ±2°C (at shipment)							
Phase Noise [dBc / Hz (typical)]	Offset		77.76	156.25	212.5	622.		1000	1250	
	10 Hz		-62	-65	-61	-51		-40	-43	
	100 H		-100	-92	-90	-79		-73	-75	
	1 KHz		-116	-108	-106	-97		-91	-88	
	10 KHz		-122	-114	-110	-102		-99	-95	
	100 KI		-124	-117	-112	-10		-99	-96	
	1 MHz		-144	-139	-133	-125		-121	-117	
10 MH		lz	-152	-147	-142	-13	4	-129	-127	
Phase Jitter			0.9	0.9	1.2 1.1		ı	1.1	1.2	
(12 KHz – 20 MHz, RMS) unit ps										
Duty Cycle			50% ±5%							
Start-up Time			5m sec max ±2 ppm max, first year at +25°C., ±10 ppm max. over 10 years							
Aging at Ta = +25°C					ıt +∠5°C., ±10	o ppm n	nax. ov	er to years	5	
Storage Temperature -55°C to +150°C  Control Voltage Function on Pad 1  Output Enable Function on Pad 2										
Control Voltage Fun	ction o	n Pau 1		Output E	-nable Fund	tion on			orno	
Control Voltage Center and Range								0.7 of V <sub>DD</sub> (min.) or no connection to enable		
		+1.5V ±1.0V 1	for $V_{DD} = 3.3V$	'			output. LVCMOS / LVTTL			
				OF Cont	OE Control on Pad 2			level.		
					OL CONTO ON 1 ad 2			0.3 of V <sub>DD</sub> (max.) to disable		
Frequency Pulling Range		±8 ppm min.					output (high impedance).			
								LVCMOS / LVTTL level.		
				Outnut F	Output Enable Time /					
Linearity		±1% typical. ±10% max			Disable Time			200 nS Max / 50 nS Max		
T		D ::: T :		2.34.0.0				1.5 pS typical		
Transfer Function		Positive Transfer		1.				(12 KHz to 20 MHz)		
Absolute Voltage		4.07/		─ Integrate	Integrated Phase Jitter		<400 fS			
		4.0V max					(1.875 KHz to 21 MHz)			
Input Impedance		770 kΩ typica	ıl						,	
Harmonics -5.0 dBc max										
1										

Other customized specifications maybe available. Please contact Dynamic Engineers Inc. for further details.